



HEX-0711

Halogen Free

GaAs Hall Sensor



1. Description

This data sheet is applied to GaAs Hall sensor that HEX.TEC co. Ltd., supplies.

2. Electrical specifications

2.1 Absolute maximum ratings

[Ta=25°C]

Parameter	Symbol	Rating	Unit
Maximum Input Voltage	Vc	10	V
Maximum Power Dissipation	Pmax	150	mW
Operating Temperature Range	Top	-40 ~ +125	°C
Storage Temperature Range	Tst	-40 ~ +150	°C

2.2 General electrical specifications

[Ta=25°C]

Parameter	Symbol	Conditions	Min	Max	Unit
Output Hall Voltage	Vh	Vin=6V, B=50mT	60	80	mV
Input Resistance	Rin	Ic = 0.1mA	650	850	Ω
Output Resistance	Rout	Ic = 0.1mA	650	850	Ω
Offset Voltage	Vo	Vin = 6V, B = 0mT	- 11	+ 11	mV

※ Vh=Vhm-Vo (Vhm : The output voltage measured at 50mT)

2.3 Other electrical specifications (For reference only)

[Ta=25°C]

Parameter	Symbol	Conditions	Min	Max	Unit
Temp. Coeff. of VH	αVh	Average value between Ta = 25~125°C, B=50mT, Ic=5mA	-	- 0.06	%/°C
Temp. Coeff. of Rin	αRin	Average value between Ta = 25~125°C, B=0mT, Ic=0.1mA	-	0.3	%/°C
Linearity	ΔK	B=0.1TG/0.5T Ic=5mA	-	2	%

$$\text{※ } \alpha_{Rin} : \frac{1}{Rin[T1]} \times \frac{Rin[T2] - Rin[T1]}{[T2 - T1]} \times 100 \quad \text{※ } \Delta K : \frac{K[B1] - K[B2]1}{[K(B1) + K(B2)]/2} \times 100$$

$$\text{※ } \alpha_{Vh} : \frac{1}{Vh[T1]} \times \frac{Vh[T2] - Vh[T1]}{[T2 - T1]} \times 100$$

T1 = 25°C, T2 = 125°C

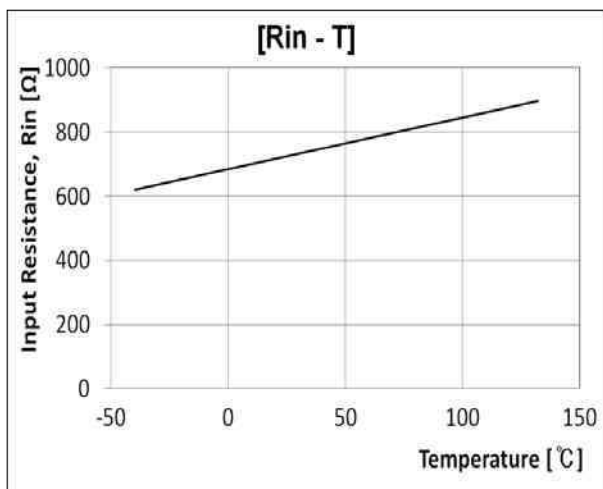
K = Vh / (Ic*B)

B1 = 0.5T, B2 = 0.1T

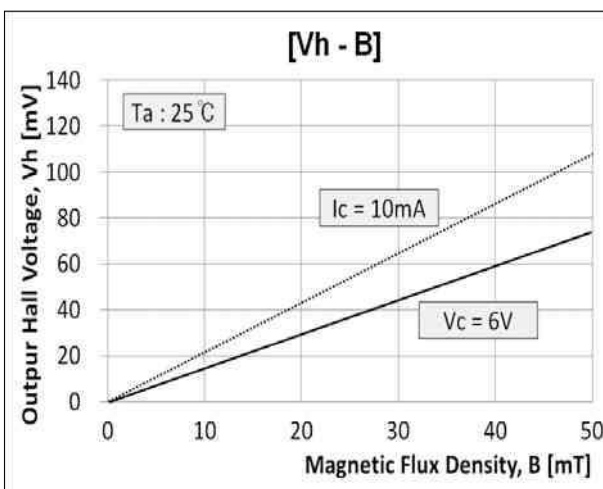


2.4 Characteristics graphs

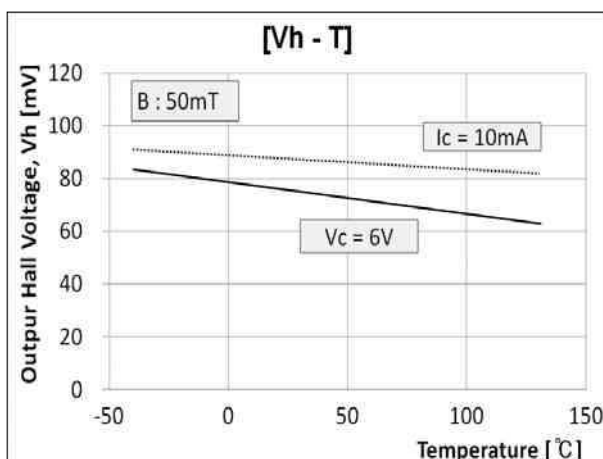
■ Rin-T



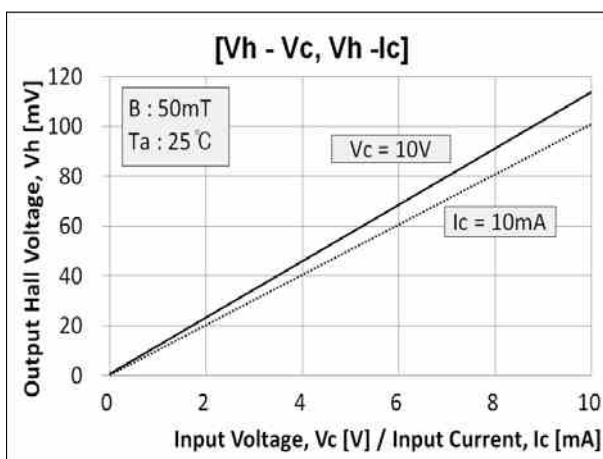
■ Vh-B



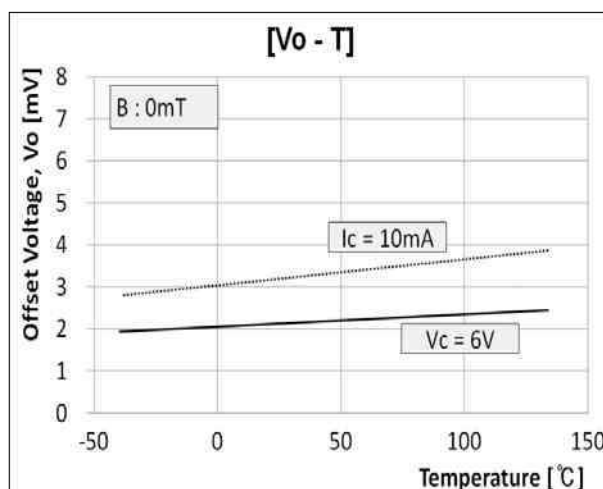
■ Vh-T



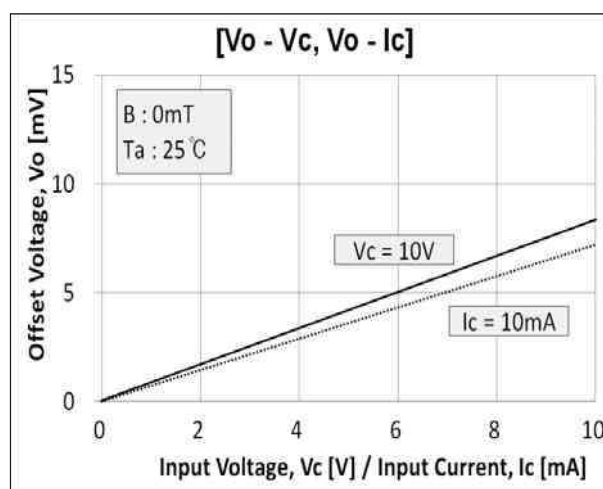
■ Vh-Vc, Vh-Ic



■ Vo-T [For reference only]



■ Vo-Vc, Vo-Ic [For reference only]



※Magnetic Flux Density 1[mT] = 10 [G]



3. Method for mounting

3.1 Lead frame

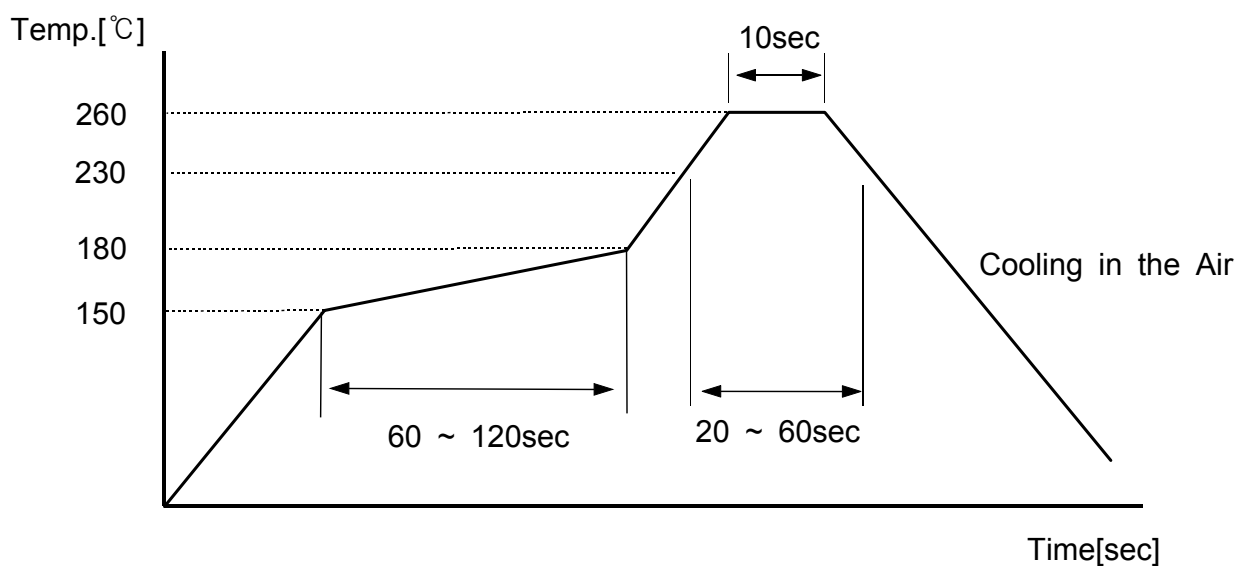
- 1) The material of lead frame is phosphor bronze alloy and the wire bonded surface is plated by silver. The minimum thickness of silver plating is $2.0\mu\text{m}$.
- 2) Lead frame is plated by pure Sn and the thickness is controlled by $4\sim 12\mu\text{m}$.

3.2 Soldering conditions on PCB

- 1) No rapid heating and cooling is desired.
- 2) Preheating is recommended for 60 ~ 120secs at $150\sim 180^\circ\text{C}$.
- 3) Reflowing is recommended for 10seconds at 260°C .

3.3 Soldering method and temperature

Items	Method	Temperature
Reflow	Soldering by passing the heated zone	Max 260°C in 10sec
Solder Iron	Soldering by solder-iron	Max 350°C in 3sec



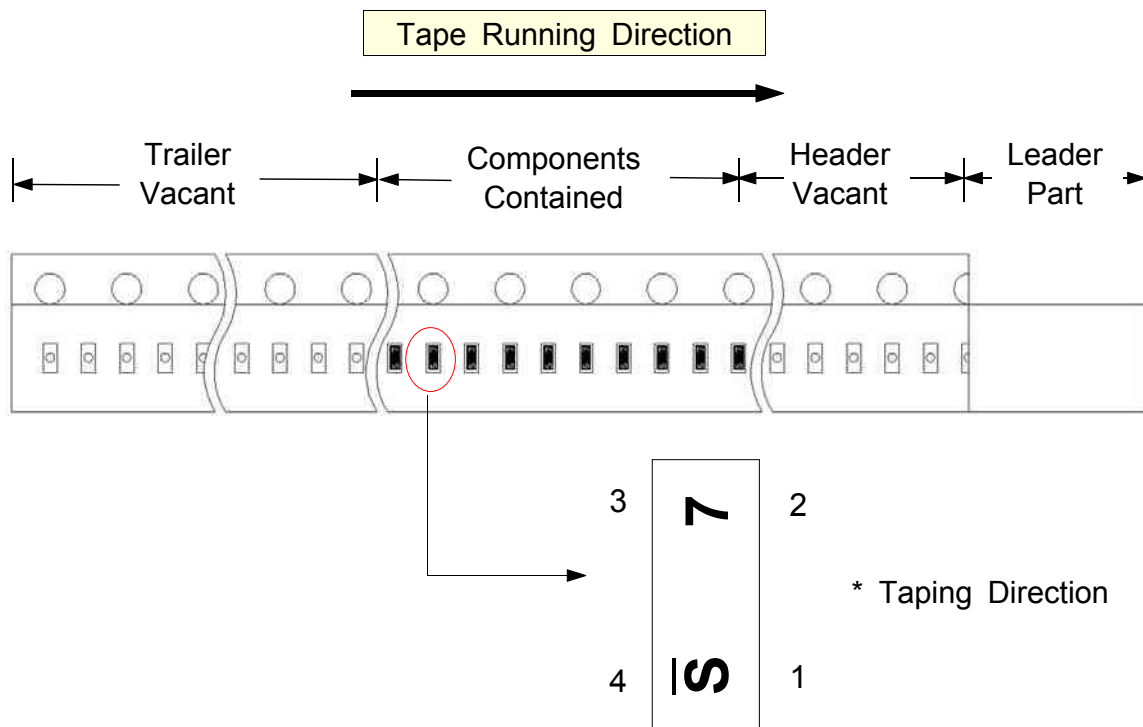
[Reflow Method]



4. Packaging

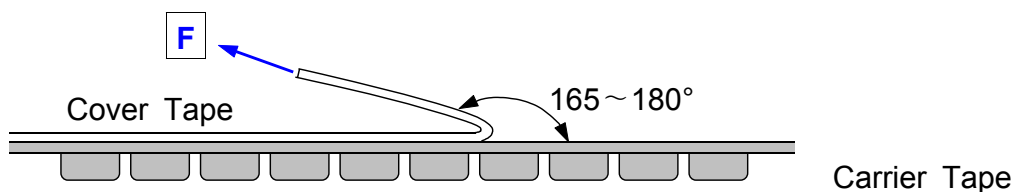
4.1 Taping

- 1) HEX-0711 should be packed and marking is possible to see through cover tape.
- 2) At least, 100mm vacant parts are made both front and rear side of tape.



4.2 Taping specifications

- 1) Pull Strength(F) = 20~70g



- 2) Devices should not run out of a pocket when tape is bent down 15mm curvature.
- 3) Devices should not stick to cover tape.
- 4) Devices should be kept below 40°C and below RH80% in the shade.
- 5) Tape has no joint.